



TO-5 RELAYS ESTABLISHED RELIABILITY MILITARY DPDT



SERIES	RELAY TYPE
412	DPDT basic relay
412D	DPDT relay with internal diode for coil transient suppression
412DD	DPDT relay with polarity reversal protection and coil transient suppression diode
412T	DPDT relay with internal transistor driver and coil transient suppression diode

DESCRIPTION

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed expressly for high-density PC board mounting, its small size and low coil power dissipation make the 412 relay one of the most versatile ultraminiature relays available.

The following unique construction features and manufacturing techniques provide excellent resistance to environmental extremes and overall high reliability.

The 412 feature:

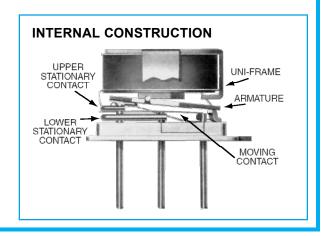
- •All welded construction.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- High force/mass ratios for resistance to shock and vibration.

- Advanced cleaning techniques provide maximum assurance of internal cleanliness.
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

The Series 412D and 412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid 412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 412 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of T-R switching

ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS			
Temperature (Ambient)	–65°C to +125°C		
Vibration (General Note I)	30 g's to 3000 Hz		
Shock (General Note I)	75 g's, 6ms half sine		
Acceleration	50 g's		
Enclosure	Hermetically sealed		
Weight	0.09 oz. (2.55g) max.		





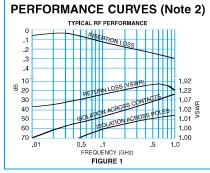
SERIES 412 GENERAL ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 2 &3)

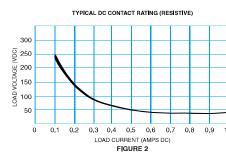
Contact Arrangement	2 Form C (DPDT)			
Rated Duty	Continuous			
Contact Resistance	0.1 ohm max. before life; 0.2 ohm max. after life at 1A/28Vdc (measured 1/8" from header)			
Contact Load Rating (DC)	Resistive: 1 A/ 28 Vdc Inductive: 200 mA/ 28 Vdc (320mH) Lamp: 100 mA / 28 Vdc (320mH) Low level: 10 to 50 μA @ 10 to 50 mV			
Contact Load Rating (AC)	Resistive: 250 mA / 115Vac, 60 and 400 Hz (Case not grounded) 100 mA / 115 Vac, 60 and 400 Hz (Case grounded)			
Contact Life Ratings	10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive 100,000 cycles min. at all other loads specified above			
Contact Overload Rating	2 A / 28 Vdc Resistive (100 cycles min.)			
Coil Operating Power	450 mW typical at nominal rated voltage			
Contact Carry Rating	Contact Factory			
Operate Time	2.0 ms max. at nominal rated coil voltage			
Release Time	412: 1.5 ms max. 412D, 412DD: 4.0 ms max.		412T: 7.5 ms max	
Contact Bounce	1.5 ms max			
Intercontact Capacitance	0.4 pf typical			
Insulation Resistance	10,000 M Ω min. between r	mutually isolated terminals		
Dielectric Strength	500 Vrms / 60 Hz @ atmospheric pressure			
Dielectric Strength	125 Vrms / 60 Hz @ 70,000 ft			
Negative Coil Transient (Vdc) 412D, 412DD, 412T	1.0 Vdc Max.			
Diode P.I.V. (Vdc) 412D, 412DD, 412T	100 Vdc Min.			
	Base Voltage to Turn Off (Vdc)		0.3 min	
412T Transistor Characteristics	Emitter-Base breakdown Voltage (BV _{EBO}) (@25°C) (Vdc) 6.0 min		6.0 min	
	Collector-Base breakdown (@25°C & lc = 100 μA) (Vc	n Voltage (BV _{CBO}) dc)	75 min	



412 Series DETAILED ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 3)

BASE PART NUMBERS (412, 412D, 412DD, 412T)		412-5 412D-5 412DD-5 412T-5	412-12 412D-12 412DD-12 412T-12	412-26 412D-26 412DD-26 412T-26	
Coil Voltage	Nom.		5.0	12.0	26.5
Con voitage	Max.		5.8	16.0	32.0
Coil Resistance	412, 412D, 412T		50	390	1560
(Ohms ±10% @25°C)	412DD		39	390	1560
Coil Curent (412DD)	Min.		93.2	25.6	14.8
(mAdc@25°C)	Max.		128.2	32.8	18.5
Coil Curent (412T)	Min.		82.2	26.6	14.7
(mAdc@25°C) (Note 7)	Max.		112.1	35.8	19.8
	412,	412D	3.5	9.0	18.0
Pick-up Voltage (Vdc, Max)	412DD		3.9	10.0	19.0
, , ,	412T (Note 7)		3.5	9.0	18.0
	412, 412D,	Min.	0.14	0.41	0.89
Drop-out Voltage	412D, 412T	Max.	2.3	6.5	13.0
(Vdc)	412DD	Min.	0.6	0.9	1.4
		Max.	2.8	6.5	13.0





GENERAL NOTES

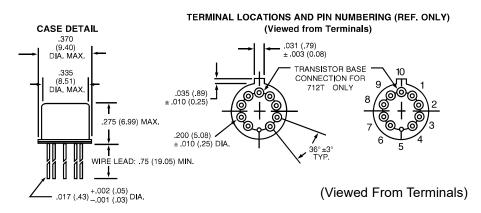
- Relay contacts will exhibit no chatter in excess of 10 µsec or transfer in excess
- of 1 µsec.

 2. "Typical" characteristics are based on available data and are best estimates. No on-going verification tests are performed.
 3. Unless otherwise specified, parameters
- are initial values.

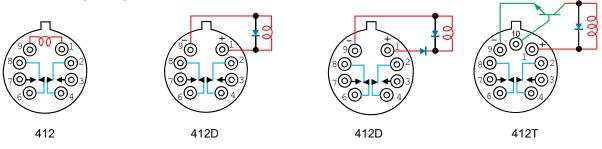
 4. Relays can be supplied with a spacer pad. See appendix.



SERIES 412 OUTLINE DIMENSIONS

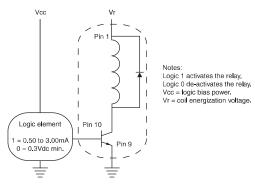


SCHEMATIC DIAGRAMS



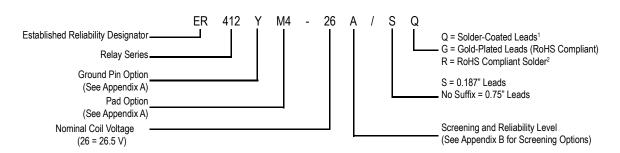
TYPICAL LOGIC INTERFACE

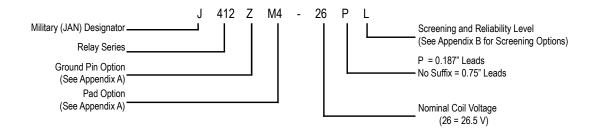
(See Note 8)





SERIES 412 PART NUMBERING SYSTEM





NOTES

- 1. RELAY CONTACTS WILL EXHIBIT NO CHATTER IN EXCESS OF 10 MSEC OR TRANSFER IN EXCESS OF 1 MSEC.
- 2. "TYPICAL" CHARACTERISTICS ARE BASED ON AVAILABLE DATA AND ARE BEST ESTIMATES. NO ON-GOING VERIFICATION TESTS ARE PERFORMED.
- 3. UNLESS OTHERWISE SPECIFIED, PARAMETERS ARE INITIAL VALUES.
- 4. FOR REFERENCE ONLY. COIL RESISTANCE NOT DIRECTLY MEASURABLE AT RELAY TERMINALS DUE TO INTERNAL SERIES SEMICONDUCTOR. 412DD AND 412T ONLY.
- $5. \ UNLESS\ OTHERWISE\ SPECIFIED,\ RELAYS\ WILL\ BE\ SUPPLIED\ WITH\ EITHER\ GOLD-PLATED\ OR\ SOLDER-COATED\ LEADS.$
- 6. THE SLASH AND CHARACTERS APPEARING AFTER THE SLASH ARE NOT MARKED ON THE RELAY.
- 7. LIMIT BASE EMITTER CURRENT TO 15 mADC.
- 8. APPLICABLE TO ALL COIL VOLTAGES. SEE BASE CURRENT TO TURN ON.
- 9. SCREENED HI-REL VERSIONS AVAILABLE. CONTACT FACTORY.

APPENDIX A: Spacer Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
Ø.150		ER412	.295 (7.49)
-→ [3.81] - (REF)	 	712, RF300, RF, RF700, RF703	.300 (7.62)
000	Dim H MAX	ER422, 722	.305 (7.75)
		ER432	.400 (10.16)
		732, RF303	.410 (10.41)
"M4" Spacer Pad for TO-5	UU U UU	RF312	.350 (8.89)
	Dim H MAX	ER411	.295 (7.49)
		RF311	.300 (7.62)
"M4"Spacer Pad for TO-5		RF331	.410 (10.41)
_	Dim H MAX	172	.305 (7.75)
		ER114, J114	.300 (7.62)
		ER134, J134	.400 (10.16)
0 0 0		RF100	.315 (8.00)
"M4" Spacer Pad for Centigrid [®]		RF103	.420 (10.67)
.156 → [3.96] → (REF)		122C, A152	.320 (8.13)
	T	ER116C, J116C	.300 (7.62)
256 [6.5] (REF)	Dim H MAX	ER136C, J136C	.400 (10.16)
		RF180	.325 (8.25)
"M9"Spacer Pad for Centigrid®		A150	.305 (7.75)

Notes

- 1. Spacer pad material: Polyester film.
- To specify an "M4" or "M9" spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (.25 mm).
- 5. Add 10 m Ω to the contact resistance shown in the datasheet.
- 6. Add 0.01 oz. $(0.25\ g)$ to the weight of the relay assembly shown in the datasheet.

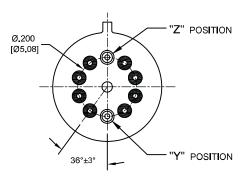
APPENDIX A: Spreader Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
		ER411T, ER412, J412	.388 (9.86)
.150	Dim H MAX	712	.393 (9.99)
[3.81]	[0.36] (REF)	ER432, J432	.493 (12.52)
[2.54]	.370 [9.4] MIN	732	.503 (12.78)
"M" Spreader Pad <u>5</u> / <u>6</u> /	<u> </u>	J421, J422, ER422, 722	.398 (10.11)

Notes

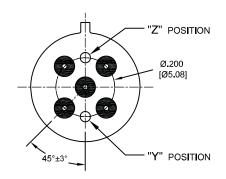
- 1. Spreader pad material: Diallyl Phthalate.
- 2. To specify an "M", "M2" or "M3" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
- 3. Dimensions are in inches (mm).
- 4. Unless otherwise specified, tolerance is ± .010" (0.25 mm).
- $\underline{5}$ /. Add 25 m Ω to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.
- $\overline{2}$ /. Add 50 m Ω to the contact resistance shown in the datasheet.
- 8/. Add 0.025 oz (0.71 g) to the weight of the relay assembly shown in the datasheet.
- 9/. M3 pad to be used only when the relay has a center pin (e.g. ER411M3-12A, 722XM3-26.)

APPENDIX A: Ground Pin Positions



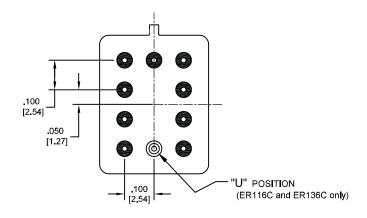
TO-5 Relays:

ER412, ER412T, ER422, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF341, RF312, RF332, RF310, RF313, RF320, RF323, SI800, SI803, RF700, RF703



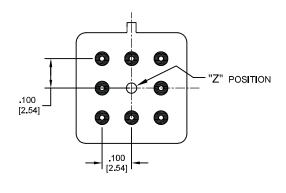
TO-5 Relays:

ER411, RF311, RF331



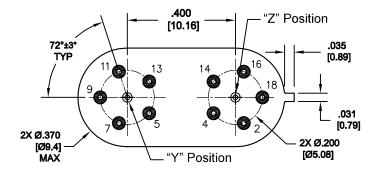
Centigrid® Relays:

RF180, ER116C, 122C, ER136C



Centigrid® Relays:

RF100, RF103, ER114, ER134, 172



Loopback Relays: LB363

- Indicates ground pin position
- Indicates glass insulated lead position
- Indicates ground pin or lead position depending on relay type

NOTES

- 1. Terminal views shown
- 2. Dimensions are in inches (mm)
- 3. Tolerances: ± .010 (±.25) unless otherwise specified
- 4. Ground pin positions are within .015 (0.38) dia. of true position
- 5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
- 6. Lead dia. 0.017 (0.43) nom.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Teledyne Relays:

ER412-12A ER412-26A ER412-5A J412-26L J412-26M J412-26WM J412D-12M J412D-26M J412DD-26M

ER412YM-26A/SQ ER412DYM4-26A/SQ ER412D-12A-SG J412DDM26L J412-5M J412-12M J412D-5M ER412D
12A J412D-12L ER412D-5A J412D-5L J412-12L J412-5L J412D-26L J412-5WL ER412DDXM4-5A/SG ER412D
26B ER412DM-12B/Q ER412T-12A ER412D-5B/SQ ER412DYM4-26B/Q ER412D-26A